# **Small Forward Converter for Lab Measures**

Zoran Zivanovic and Vladimir Smiljakovic IMTEL KOMUNIKACIJE AD Bul. Mihajla Pupina165b, 11070 Belgrade, Serbia zoki@imtelkom.ac.rs smiljac@imtelkom.ac.rs D

**ABSTRACT:** We have given the outcome of the work on a design of a small forward converter. We have used lab measures, to build converter for generating a design. The steps we have used are enumerated and a correct recording of the procedures are carried out in the work with results. These steps can serve as a platform for future research.

Keywords: DC/DC Converter, Forward, Efficiency

Received: 3 October 2022, Revised 10 December 2022, Accepted 19 December 2022

DOI: 10.6025/ed/2023/12/1/7-14

Copyright: with Author

### 1. Introduction

The most frequently used DC/DC converter is a single switch forward converter, especially for telecom use with input voltage range from 18 to 36 or 36 to 72V. It is used in Digital Radio Relay Systems and Radio Base Stations. From few watts to a couple hundred watts, with one or multiple outputs, they need to have high efficiency and high density.

Unlike the flyback converter they have two magnetic components: the transformer and the output inductor.

### 2. Principle of Forward Converter

The basic forward converter circuit is shown in Fig. 1. During the time when the primary power switch (MOSFET Q) is on, the energy is transferred to the secondary. Diode D1 is forward biased and the current flows through inductor L to the capacitor C and the load. When the power switch turns off, diode D1 is reverse biased and forward biased diode D2 provides freewheeling path for inductor current from input and stored in the transformer. Capacitor C acts as a reservoir and holds the output voltage nearly constant.

### 3. Design and Analysis

The task is to design a 10W forward converter using current mode control IC with careful choice of operating parameters and components. Achieving the efficiency as much as possible near 85% is the primary objective. The footprint size must be smaller

than 50x25mm.

First we choose the switching frequency to be around 340 kHz, which is a compromise between the efficiency and size. Knowing that, a good choice of core for the transformer and the inductor is RM4, N49 material from TDK-EPCOS.



Figure 1. Forward converter

Design specifications are given in Table 1.

|                      |                  | Min | Тур | Max |     |
|----------------------|------------------|-----|-----|-----|-----|
| Input voltage        | V <sub>IN</sub>  | 18  | 24  | 36  | V   |
| Output voltage       | Vo               |     | 5   |     | V   |
| Output current       | Io               | 0.1 | 2   |     | Α   |
| Output current limit | I <sub>OCL</sub> |     | 2.4 |     | Α   |
| Full load efficiency | η                |     | 85  |     | %   |
| Switching frequency  | f <sub>SW</sub>  |     | 340 |     | kHz |

|                           |                   | Max  | Тур  | Min  |    |
|---------------------------|-------------------|------|------|------|----|
| Duty cycle                | D                 | 0.43 | 0.32 | 0.21 |    |
| Number of primary turns   | N <sub>P</sub>    |      | 12   |      |    |
| Number of secondary turns | Ns                |      | 8    |      |    |
| Primary RMS current       | I <sub>PRMS</sub> | 1.00 | 0.86 | 0.70 | Α  |
| Secondary RMS current     | I <sub>SRMS</sub> | 1.31 | 1.13 | 0.92 | Α  |
| Output inductance         | L                 |      | 21   |      | μН |
| Number of induct. turns   | N                 |      | 14   |      |    |

## Table 2. Basic Parameters

The main contributors to power losses are transformer, output inductor, power switch, current sensing and secondary rectifiers.

Starting from design specifications we will now calculate basic parameters for the transformer and output inductor (Table 2).

Now it is time to wind the transformer and output inductor. We will use 2 parallel strands of 0.3mm copper wire for the primary and the secondary, in order to minimize copper losses. For the output inductor we will use 3 parallel strands of 0.3mm copper wire.

Knowing specific core losses we can now calculate the losses in both magnetic components (Table 3). Total transformer power loss at 24V input voltage is 188mW. This results in approximately  $24^{\circ}$  C rise above ambient temperature. The temperature rise on the inductor is  $19^{\circ}$  C Satisfied with results, we will keep the chosen core geometry.

|                      |                   | Max | Тур  | Min |                   |
|----------------------|-------------------|-----|------|-----|-------------------|
| Core effect. volume  | VE                |     | 0.29 |     | cm <sup>3</sup>   |
| Specific core losses | P <sub>V</sub>    |     | 0.32 |     | W/cm <sup>3</sup> |
| Primary resistance   | R <sub>P</sub>    |     | 66   |     | mΩ                |
| Secondary resistance | R <sub>S</sub>    |     | 45   |     | mΩ                |
| Core loss            | P <sub>CORE</sub> |     | 93   |     | mW                |
| Primary loss         | P <sub>PRI</sub>  | 66  | 49   | 33  | mW                |
| Secondary loss       | P <sub>SEC</sub>  | 77  | 57   | 38  | mW                |
| Inductor loss        | P <sub>IND</sub>  |     | 157  |     | mW                |

Table 3. Transformer And Inductor Losses

As the next step we will compute the power losses for power switch IRFR3410 (Table 4).

| IRFR3410                |                  |     | Тур |     |    |
|-------------------------|------------------|-----|-----|-----|----|
| ON resistance           | R <sub>DS</sub>  |     | 39  |     | mΩ |
| Reverse transfer capac. | C <sub>RSS</sub> |     | 250 |     | pF |
| Conduction loss         | P <sub>CON</sub> | 59  | 43  | 29  | mW |
| Switching loss          | P <sub>SW</sub>  | 78  | 138 | 300 | mW |
| Total loss              | P <sub>TOT</sub> | 137 | 181 | 329 | mW |

### Table 4. IRFR3410 Power Losses

Obviously MOSFET IRFR3410 is a good choice because of the low power losses.

For current sensing we can use a current sense resistor or a current transformer. For simplicity and smaller losses we will use current sense resistor. Power dissipated in current sense resistor is given in Table V.

|                          |                 | Max | Тур | Min |    |
|--------------------------|-----------------|-----|-----|-----|----|
| Current sense resistance | R <sub>CS</sub> |     | 0.5 |     | Ω  |
| CS resistance loss       | P <sub>CS</sub> | 500 | 370 | 245 | mW |

Table 5. Current sense resistor power losses

Dissipation of 500mW at low line will reduce efficiency about 4%. For higher efficiency the circuit shown in Figure 2 will be used. Resistors  $R_2$  and  $R_3$  bias the current sense resistor  $R_1$  reducing a current sense amplitude, so the sense resistor can be three times smaller. As a result we have smaller power loss. The new calculation results are given in Table 6.

With this simple circuit the dissipation is reduced significantly (from 500 to 165mW at low line).

At the end we will calculate the power losses for secondary rectifier Schottky diode MBRD660CTG (Table 7).

Electronic Devices Volume 12 Number 1 March 2023

9



Figure 2. Current sense circuit with bias

|                          |                 | Max | Тур | Min |    |
|--------------------------|-----------------|-----|-----|-----|----|
| Current sense resistance | R <sub>CS</sub> |     | 165 |     | mΩ |
| CS resistance loss       | P <sub>CS</sub> | 165 | 122 | 81  | mW |

Table 6. Biased Current Sense Resistor Power Losses

| MBRD660CTG      |                            | Min | Тур | Max |   |
|-----------------|----------------------------|-----|-----|-----|---|
| Conduction loss | <b>P</b> <sub>CON</sub>    |     | 0.8 |     | W |
| Switching loss  | $\mathbf{P}_{\mathrm{SW}}$ |     | 0.4 |     | W |

| Table 7. | Rectifiers | Power | Losses |
|----------|------------|-------|--------|
|          |            |       |        |

Comparing to the other losses it is obvious that the choice of secondary rectifier is critical for the converter efficiency.

## 4. Realisation

DC/DC converter was built on FR-4 substrate with 35 copper with footprint 50x25mm. The transformer and the output inductor are wounded on through hole coil formers according to calculations. Current sense resistor (with bias) is adopted for primary current sensing.

Using lab power supply 0-60V/3A and resistive load we have measured full load efficiency at various input voltages.

The results are given in Table 8. The efficiency is around 83%, which is not so bad. Simultaneously with efficiency measurements we have recorded the waveforms at the point of interest.

|               |                 |       | Тур   |       |   |
|---------------|-----------------|-------|-------|-------|---|
| Input voltage | V <sub>IN</sub> | 18    | 24    | 36    | V |
| Input current | I <sub>IN</sub> | 0.679 | 0.50  | 0.340 | А |
| Input power   | P <sub>IN</sub> | 12.22 | 12.00 | 12.24 | W |
| Efficiency    | η               | 81.82 | 83.33 | 81.70 | % |

| fficiency |
|-----------|
|           |













Electronic Devices Volume 12 Number 1 March 2023



Figure 6. Drain voltage and current waveform at  $24\mathrm{V}$ 



Figure 7. Drain voltage and current waveform (offset) at 24V

The drain waveforms of primary power switch at full load and input voltages of 18, 24 and 36V are given in Figs. 3, 4 and 5 respectively. Drain current waveforms can be seen in Figs. 6 and 7.

| Temperature (°C) |    |  |  |  |
|------------------|----|--|--|--|
| Ambient          | 31 |  |  |  |
| MOSFET           | 55 |  |  |  |
| Diode            | 81 |  |  |  |
| Transformer      | 58 |  |  |  |
| Inductor         | 57 |  |  |  |

Table 9. Temperature of critical components

At full load, input voltage of 24V and convection cooling we have measured the temperatures of critical components using thermocouple. The results are given in Table 9.

| t(s)                 | 20  | 40  | 60  | 80  | 100 | 120 |
|----------------------|-----|-----|-----|-----|-----|-----|
| V <sub>sd</sub> (mV) | 463 | 472 | 480 | 486 | 491 | 495 |

#### Table 10. Mosfet Vsd

| t(s)                | 20  | 40  | 60  | 80  | 100 | 120 |
|---------------------|-----|-----|-----|-----|-----|-----|
| V <sub>f</sub> (mV) | 103 | 130 | 142 | 150 | 155 | 158 |

#### Table 11. Diode Vf

Using curve-fitting software we can find that at t = 0 MOSFET diode voltage is  $V_{sdHOT} = 452$ mV and output diode voltage  $V_{fHOT} = 79$ mV. In a cold state we have measured Vsd COLD = 512mV and Vf COLD = 184mV. Knowing temperature coefficients for MOSFET diode  $k_1 = -2.2$  mV/and for output diode  $k_2 = -1.8$  mV/junction temperature for MOSFET using equation

MOSFET and diode junction temperature can be done more precisely using DMM and stopwatch. DMM must have diode threshold measurement option. First with power off and no load we will measure the forward voltages of FET and diode and ambient temperature.

When the converter reach the steady-state condition, we will turn the power off and remove the load simultaneously starting the stopwatch. At every 20 seconds the forward voltage needs to be measured. The procedure was done for FET and output diode. The results are given in Tables 10 and 11.

$$T_{JMOSFET} = T_{amb} + \frac{(V_{sdHOT} - V_{sdCOLD})}{k_1} = 58^{\circ}C$$

Similarly for output diode we have

$$T_{JDIODE} = T_{amb} + \frac{\left(V_{fHOT} - V_{fCOLD}\right)}{k_2} = 89^{\circ}C$$

The results are showing sufficient thermal margin for all components. At the maximum ambient temperature of 55°C the output diode junction temperature will be 113°C which is OK, but we can consider changeover to FR-4 substrate with 70µm copper and bigger heatsink surface.

The picture of converter prototype is given in Figure 8.

#### 5. Conclusion

In this paper the design and analysis of 10W forward converter are presented.

The prototype was built and tested. The results verified that the full load efficiency is about 83%.

Further improvements are possible thorough Active Clamp Reset with controller change and Synchronous Rectifier in the secondary. The efficiency will go over 90%.

#### Acknowledgement

The work is partially supported by the Serbian Ministry of Education and Science (Project III-44009).

Electronic Devices Volume 12 Number 1 March 2023



Figure 8. Converter prototype

## References

[1] Texas Instruments, "Low Power BiCMOS Current Mode PWM", SLUS270d Data Sheet, www.ti.com

[2] Robert W. Erickson, Dragan Maksimovi, Fundamentals of Power Electronics, Second Edition, Colorado, Kluwer Academic Publishers 2004.

[3] TDK-EPCOS, "Ferrites and accessories RM4", Data Sheet, www.epcos.com

[4] Texas Instruments, Power Transformer Design, Application Note SLUP126, www.ti.com

[5] David Magliocco, "Semiconductor Temperature Measurement in a Flyback Power Supply", *Switching Power Magazine*, 2005.